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Low Voltage 1-of-8 Decoder/Demultiplexer

74LVX138

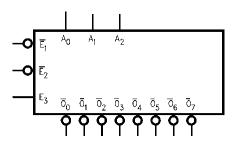
General Description

The LVX138 is a high-speed 1-of-8 decoder/demultiplexer. This device is ideally suited for high-speed bipolar memory chip select address decoding. The multiple input enables allow parallel expansion to a 1-of-24 decoder using just three LVX138 devices or a 1-of-32 decoder using four LVX138 devices and one inverter.

Features

- Input Voltage Level Translation from 5 V to 3 V
- Ideal for Low Power/Low Noise 3.3 V Applications
- Guaranteed Simultaneous Switching Noise Level and Dynamic Threshold Performance
- These Devices are Pb-Free and are RoHS Compliant

Logic Symbols



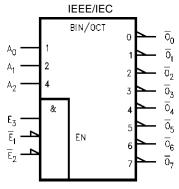


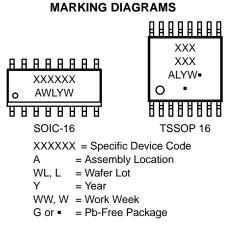
Figure 1. Logic Symbols





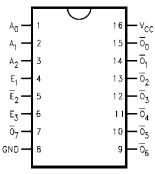
SOIC-16, 150 mils CASE 751BG

TSSOP 16 CASE 948AH



(Note: Microdot may be in either location)

CONNECTION DIAGRAM



PIN DESCRIPTIONS

Pins	Function
$A_0 - A_2$	Address Inputs
$E_1 - E_2$	Enable Inputs
E_3	Enable Input
$\overline{O}_0 - \overline{O}_7$	Outputs

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

<u>www.oi</u>

Functional Description

The LVX138 high-speed 1-of-8 decoder/demultiplexer accepts three binary weighted inputs (A₀, A₁, A₂) and, when enabled, provides eight mutually exclusive active-LOW outputs (\overline{O}_0 – \overline{O}_7). The LVX138 features three Enable inputs, two active-LOW (\overline{E}_1 , \overline{E}_2) and one active-HIGH (E₃).

All outputs will be HIGH unless \overline{E}_1 and \overline{E}_2 are LOW and E_3 is HIGH.

The LVX138 can be used as an 8-output demultiplexer by using one of the active LOW Enable inputs as the data input and the other Enable inputs as strobes. The Enable inputs which are not used must be permanently tied to their appropriate active-HIGH or active-LOW state.

TRUTH TABLE

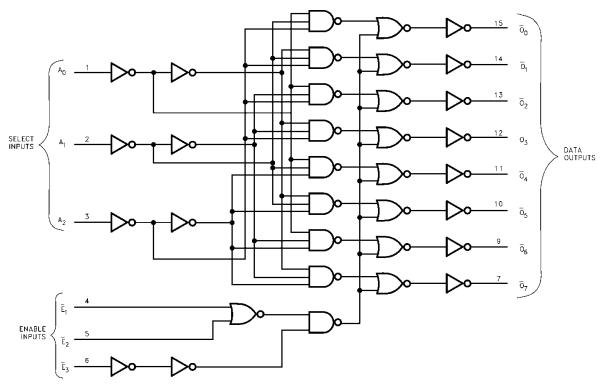
		Inp	uts						Out	outs			
E ₁	Ē ₂	E ₃	A ₀	A ₁	A ₂	O ₀	<u>0</u> 1	0 ₂	\overline{O}_3	0 ₄	<u>0</u> 5	O ₆	<u>0</u> 7
H X X	X H X	X X L	X X X	X X X	X X X	ΗΗΗ	H H H	ΗΗΗ	ΗΗΗ	ΗΗΗ	ΗΗΗ	ΗΗΗ	ΤТΤ
L L L	L L L	нтт	L H L H	L L H H	L L L	L H H	H L H H	H H L H	H H L	H H H H	H H H H	H H H	н н н н
L L L	L L L	ннн	L H L H	L L H H	H H H H	H H H H	H H H	H H H H	H H H H	L H H	H L H H	H L H	H H L

H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Figure 2. Logic Diagram

MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to +6.5	V
V _{IN}	DC Input Voltage		-0.5 to +6.5	V
V _{OUT}	DC Output Voltage		-0.5 to V _{CC} + 0.5	V
I _{IN}	DC Input Current, per Pin		±20	mA
I _{OUT}	DC Output Current, per Pin		±25	mA
I _{CC}	DC Supply Current, V_{CC} and GND Pins		±75	mA
I _{IK}	Input Clamp Current		-20	mA
Ι _{ΟΚ}	Output Clamp Current		±20	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
ΤJ	Junction Temperature Under Bias		+150	°C
θ_{JA}	Thermal Resistance (Note 1)	SOIC-16 TSSOP 16	126 159	°C/W
PD	Power Dissipation in Still Air at 25 °C	SOIC-16 TSSOP 16	995 787	mW
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V_{ESD}	ESD Withstand Voltage (Note 2)	Human Body Model Charged Device Model	2000 N/A	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

 Measured with minimum pad spacing on an FR4 board, using 76mm-by-114mm, 2-ounce copper trace no air flow per JESD51-7.
HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	DC Supply Voltage	2.0	3.6	V
V _{in}	DC Input Voltage (Note 3)	0	5.5	V
V _{out}	DC Output Voltage (Note 3)	0	V _{CC}	V
T _A	Operating Temperature	-40	+85	°C
t _r , t _f	Input Rise and Fall Time	0	100	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

3. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS

					-	T _A = 25 °C	;	T _A = -40	to 85 °C	
Symbol	Parameter	Cond	litions	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit
V _{IH}	HIGH Level Input Voltage			2.0 3.0 3.6	1.5 2.0 2.4			1.5 2.0 2.4		V
V _{IL}	LOW Level Input Voltage			2.0 3.0 3.6			0.5 0.8 0.8		0.5 0.8 0.8	V
V _{OH}	HIGH Level Output Voltage	$V_{IN} = V_{IL}$ or V_{IH}	$\begin{split} I_{OH} &= -50 \ \mu\text{A} \\ I_{OH} &= -50 \ \mu\text{A} \\ I_{OH} &= -4 \ \text{mA} \end{split}$	2.0 3.0 3.0	1.9 2.9 2.58	2.0 3.0 -		1.9 2.9 2.48		V
V _{OL}	LOW Level Output Voltage	$V_{IN} = V_{IL}$ or V_{IH}	$I_{OL} = 50 \ \mu A$ $I_{OL} = 50 \ \mu A$ $I_{OL} = 4 \ m A$	2.0 3.0 3.0		0.0 0.0 -	0.1 0.1 0.36		0.1 0.1 0.44	V
I _{IN}	Input Leakage Current	V _{IN} = 5.5 V o	or GND	3.6	-	-	±0.1	-	±1.0	μΑ
I _{CC}	Quiescent Supply Current	$V_{IN} = V_{CC}$ or	GND	3.6	-	-	4.0	-	40.0	μΑ

NOISE CHARACTERISTICS (Note 4)

		CL	v _{cc}	T _A = 2	25°C	
Symbol	Characteristic	(pF)	(V)	Тур	Limit	Unit
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	50	3.3	0.3	0.5	V
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	50	3.3	-0.33	-0.5	V
V _{IHD}	Minimum HIGH Level Dynamic Input Voltage	50	3.3	-	2.0	V
V _{ILD}	Maximum LOW Level Dynamic Input Voltage	50	3.3	-	0.8	V

4. Input tr = tf = 3 ns

AC ELECTRICAL CHARACTERISTICS

		CL	v _{cc}		T _A = 25 °C	;	$T_A = -40$	to 85 °C	
Symbol	Parameter	(pF)	(V)	Min	Тур	Max	Min	Max	Unit
t _{PLH} ,	Propagation Delay Time A_n to \overline{O}_n	15	2.7	-	7.1	13.8	1.0	16.5	ns
t _{PHL}		50		-	9.6	17.3	1.0	20.0	
		15	3.3	-	5.5	8.8	1.0	10.5	
		50	±0.3	-	8.0	12.3	1.0	14.0	
t _{PLH} ,	Propagation Delay Time \overline{E}_1 or \overline{E}_2 to \overline{O}_n	15	2.7	-	8.8	16.0	1.0	18.5	ns
t _{PHL}		50		-	11.3	19.5	1.0	22.0	
		15	3.3	-	6.9	10.4	1.0	11.5	
		50	±0.3	-	9.4	13.9	1.0	15.0	
t _{PLH} ,	Propagation Delay Time E_3 to \overline{O}_n	15	2.7	-	8.7	16.3	1.0	19.5	ns
^t PHL		50		-	11.2	19.8	1.0	23.0	
		15	3.3	-	6.8	10.6	1.0	12.5	
		50	±0.3	-	9.3	14.1	1.0	16.0	
t _{OSHL} ,	Output to Output Skew (Note 5)	50	2.7	-	-	1.5	-	1.5	ns
toslh			3.3	-	-	1.5	-	1.5	

5. Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

74LVX138

CAPACITANCE

		T _A = 25 °C		T _A = -40			
Symbol	Parameter	Min	Тур	Max	Min	Max	Unit
C _{in}	Input Capacitance	-	4	10	-	10	pF
C _{PD}	Power Dissipation Capacitance (Note 6)	-	34	-	-	-	pF

 CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: C_{PD} x V_{CC} x I_{IN} + I_{CC}

ORDERING INFORMATION

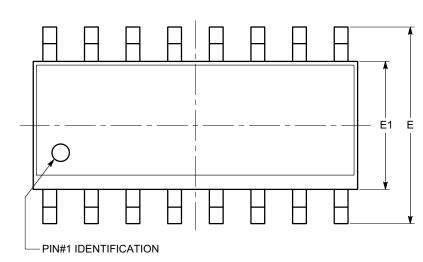
Device	Marking	Package	Shipping [†]
74LVX138MX	LVX138G	SOIC-16 (Pb-Free)	2500 Tape & Reel
74LVX138MTCX	LVX 138	TSSOP 16 (Pb-Free)	2500 Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



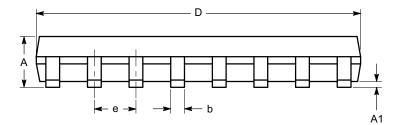
SOIC-16, 150 mils CASE 751BG ISSUE O

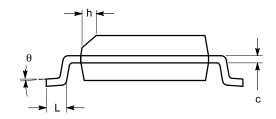
DATE 19 DEC 2008



SYMBOL	MIN	NOM	MAX
А	1.35		1.75
A1	0.10		0.25
b	0.33		0.51
с	0.19		0.25
D	9.80	9.90	10.00
E	5.80	6.00	6.20
E1	3.80	3.90	4.00
е		1.27 BSC	
h	0.25		0.50
L	0.40		1.27
θ	0°		8°

TOP VIEW





END VIEW

SIDE VIEW

Notes:

(1) All dimensions are in millimeters. Angles in degrees.

(2) Complies with JEDEC MS-012.

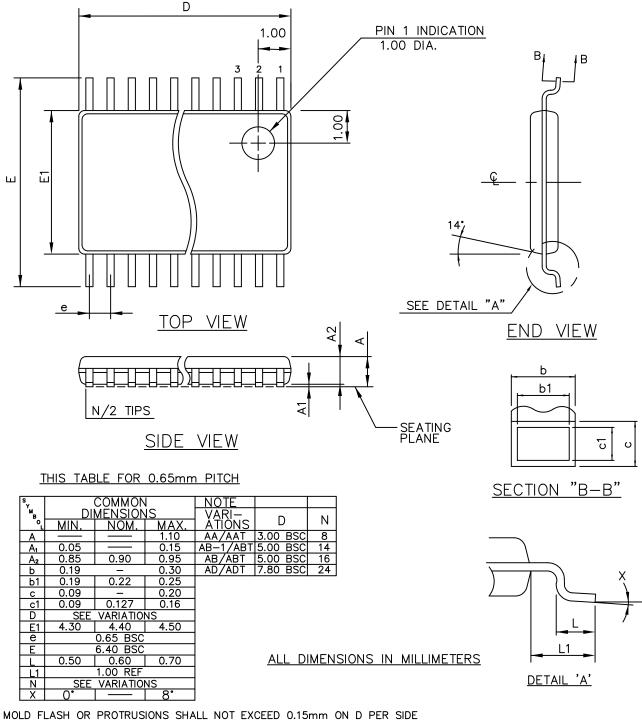
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